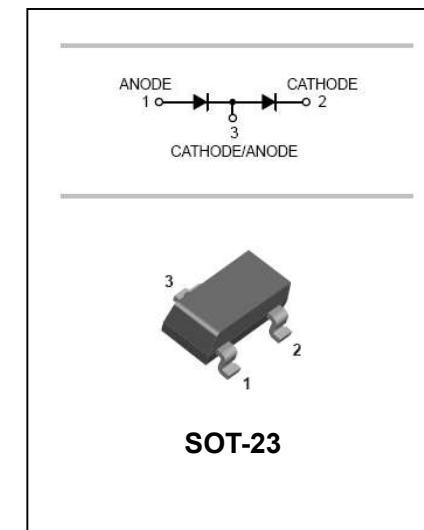


## Dual series switching diode

**BAV99****FEATURES**

- Fast switching speed Max:4ns.
- High conductance.
- Connected in series.
- Surface mount package ideally suited for automatic insertion.
- MSL1.

**APPLICATIONS**

- High-speed switching in thick and thin-film circuits.

**ORDERING INFORMATION**

Type No.	Marking	Package Code
BAV99□	A7	SOT-23

□: none is for Lead Free package;

“G” is for Halogen Free package.

**MAXIMUM RATING @ Ta=25°C unless otherwise specified**

Parameter	Symbol	Value	Unit
Reverse voltage	V <sub>R</sub>	75	V
Forward current	I <sub>F</sub>	215	mA
Peak forward surge current	I <sub>FM</sub>	500	mA
Peak repetitive reverse voltage	V <sub>RRM</sub>	75	V
Repetitive peak forward current	I <sub>FRM</sub>	450	mA
Peak forward surge current @t=1.0μs @t=1.0ms @t=1.0s	I <sub>FSM</sub>	2.0 1.0 0.5	A
Power dissipation	P <sub>d</sub>	350	mW
Thermal resistance junction to ambient air	R <sub>θJA</sub>	556	°C/W
Thermal resistance junction to case	R <sub>θJC</sub>	250	°C/W
Operating temperature	T <sub>J</sub>	150	°C
Storage temperature range	T <sub>STG</sub>	-65 to +150	°C

## Dual series switching diode

**BAV99**

### ELECTRICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Typical	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	$V_{(\text{BR})}$	$I_R=2.5\mu\text{A}$	75	-	V
Reverse voltage leakage current	$I_R$	$V_R=20\text{V}$ $V_R=75\text{V}$ $V_R=25\text{V} T_j=150^\circ\text{C}$ $V_R=75\text{V} T_j=150^\circ\text{C}$	-	25 2.5 30 50	nA $\mu\text{A}$ $\mu\text{A}$ $\mu\text{A}$
Forward voltage	$V_F$	$I_F=1\text{mA}$ $I_F=10\text{mA}$ $I_F=50\text{mA}$ $I_F=150\text{mA}$	-	715 855 1000 1250	mV
Diode capacitance	$C_D$	$V_R=0\text{V} f=1\text{MHz}$	-	2.0	pF
Reverse recovery time	$t_{rr}$	$I_F=I_R=10\text{mA}$ , $I_{rr}=0.1 \times I_R, R_L=100\Omega$	-	4.0	nS

### TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified

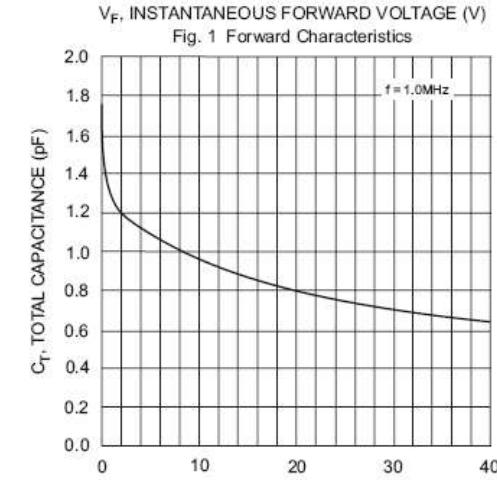
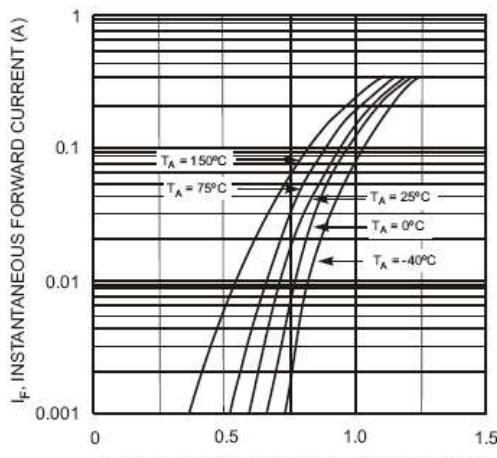


Fig. 1 Forward Characteristics  
Fig. 3 Typical Capacitance vs. Reverse Voltage

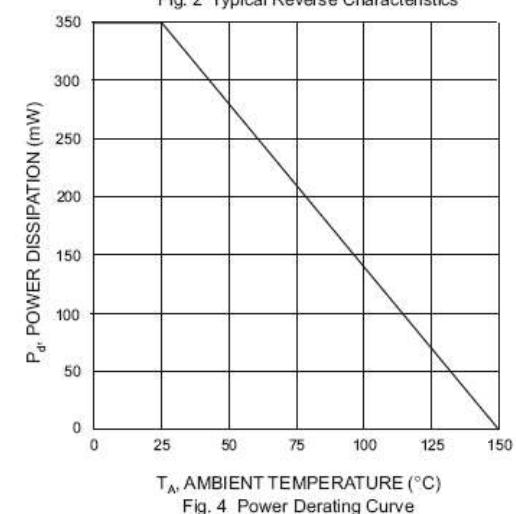
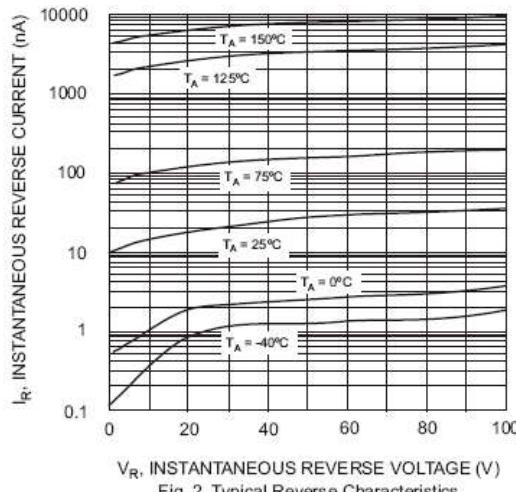


Fig. 2 Typical Reverse Characteristics  
Fig. 4 Power Derating Curve

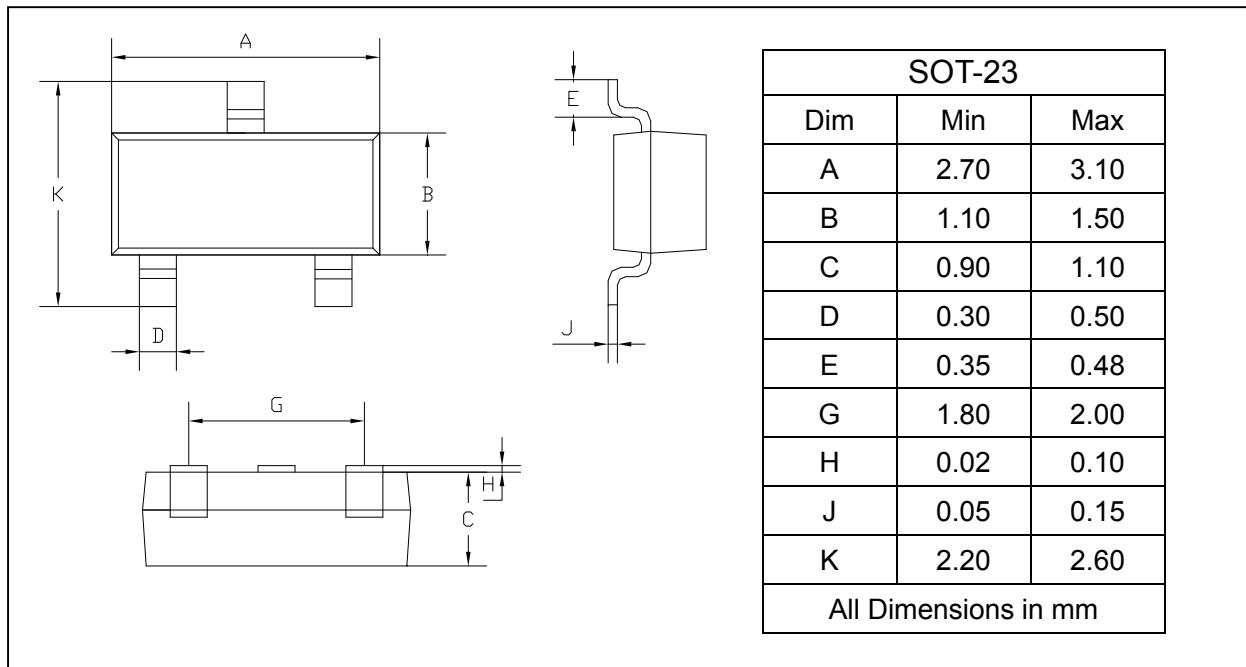
## Dual series switching diode

**BAV99**

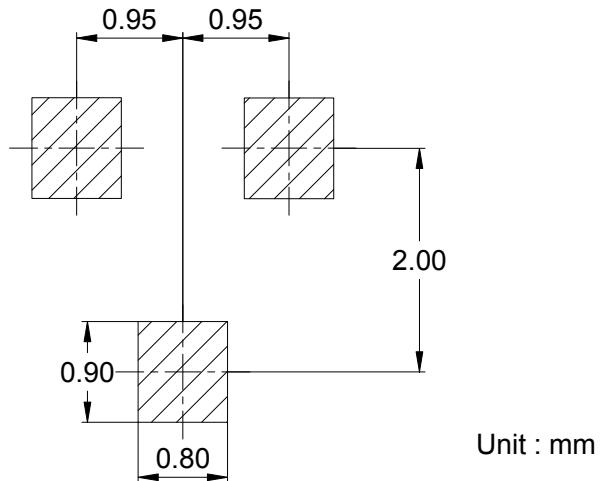
### PACKAGE OUTLINE

Plastic surface mounted package

SOT-23



### SOLDERING FOOTPRINT



### PACKAGE INFORMATION

Device	Package	Shipping
BAV99	SOT-23	3000/Tape&Reel

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